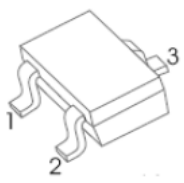
TKSS8050W

TRANSISTOR (NPN)

SOT-323



1. BASE
2. EMITTER
3. COLLECTOR

FEATURES

Complimentary toTKSS8550W

MARKING: Y1

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	40	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	1.5	A
P_C	Collector Power Dissipation	250	mW
$R_{\Theta JA}$	Thermal Resistance From Junction To Ambient	500	℃/W
T_j	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55～+150	℃

ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

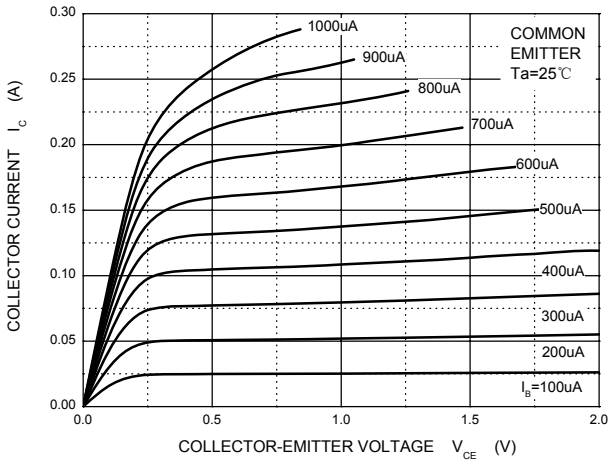
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C= 100μA, I_E=0	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C= 0.1mA, I_B=0	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=100μA, I_C=0	5			V
Collector cut-off current	I_{CBO}	V_{CB}=40V, I_E=0			0.1	μA
Collector cut-off current	I_{CEO}	V_{CE}=20V, I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}= 5V, I_C=0			0.1	μA
DC current gain	$h_{FE(1)}$	V_{CE}=1V, I_C= 100mA	120		400	
	$h_{FE(2)}$	V_{CE}=1V, I_C= 800mA	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=800mA, I_B= 80mA			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I_C=800mA, I_B= 80mA			1.2	V
Transition frequency	f_T	V_{CE}=10V, I_C= 50mA, f=30MHz	100			MHz
Collector output capacitance	C_{ob}	V_{CB}=10V,I_E=0,f=1MHz			15	pF

CLASSIFICATION OF $h_{FE(1)}$

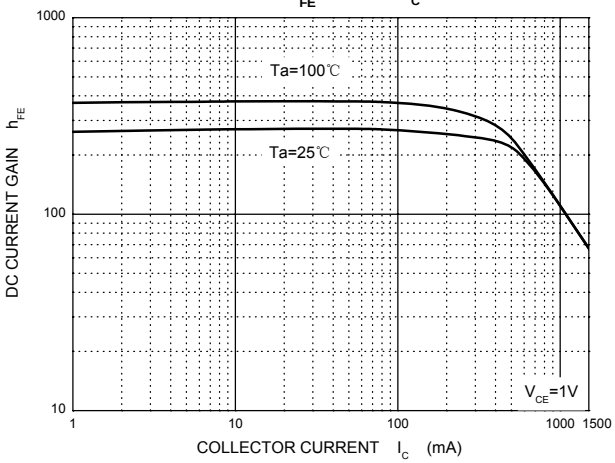
Rank	L	H	J
Range	120-200	200-350	300-400

Typical Characteristics

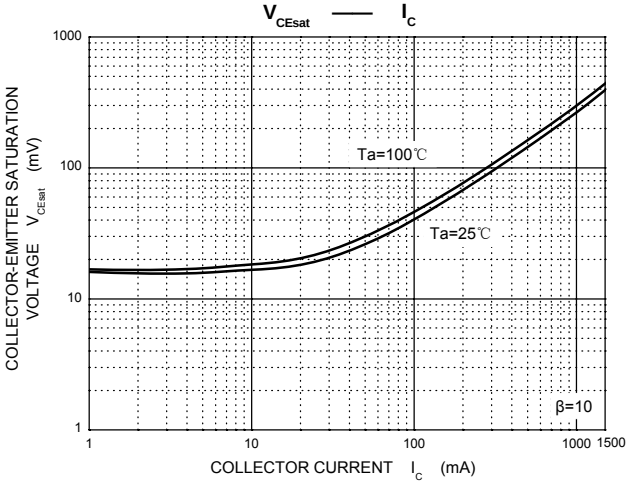
Static Characteristic



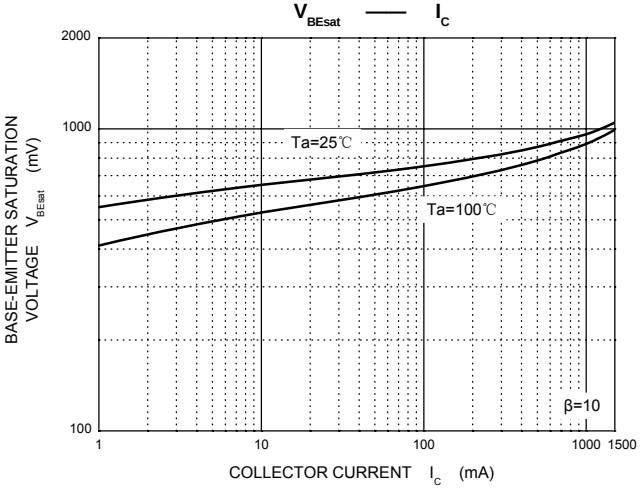
h_{FE} — I_C



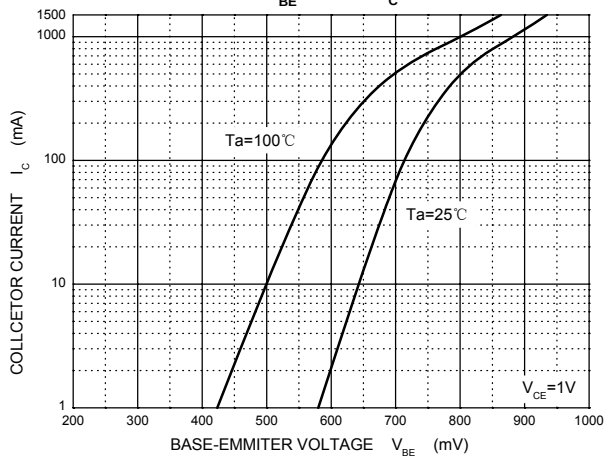
V_{CEsat} — I_C



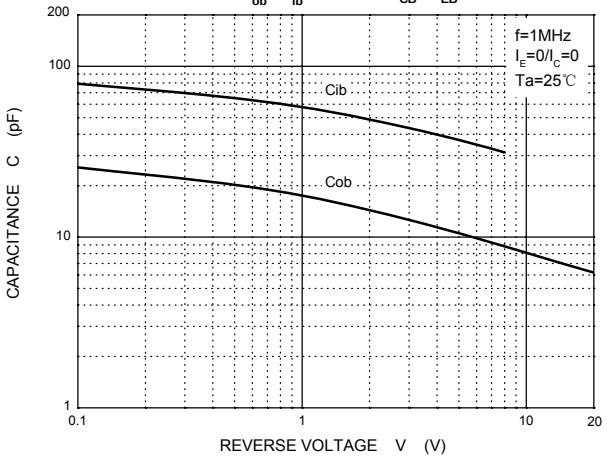
V_{BEsat} — I_C



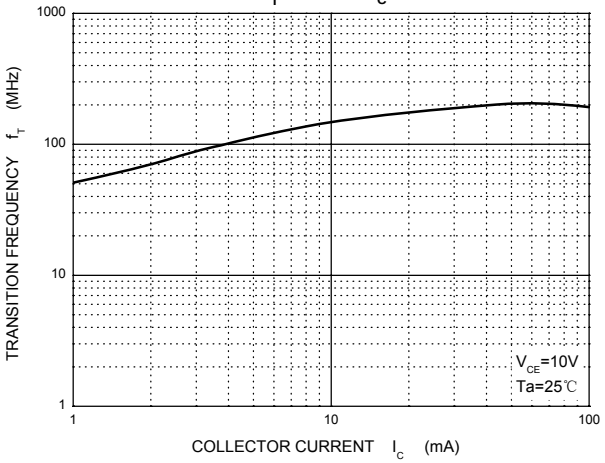
V_{BE} — I_C



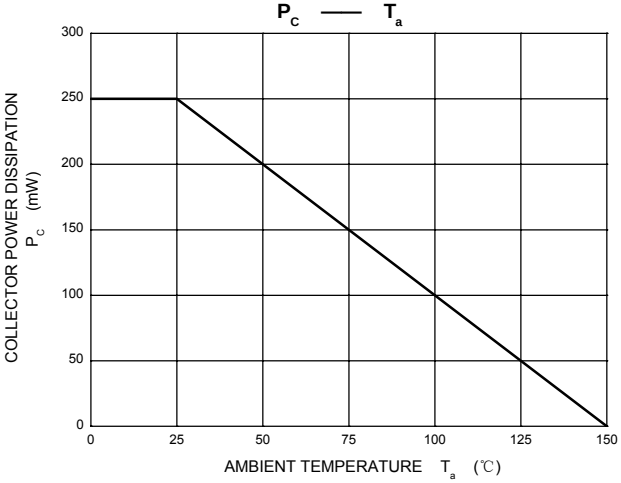
C_{ob} / C_{ib} — V_{CB} / V_{EB}



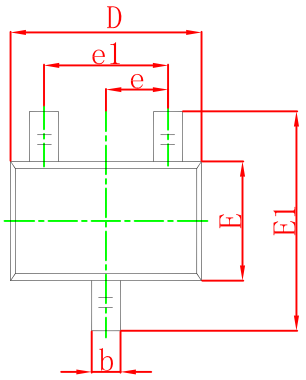
f_T — I_C

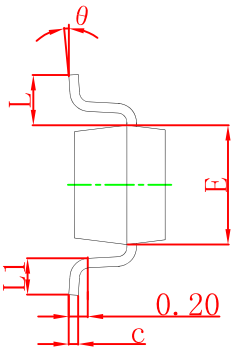


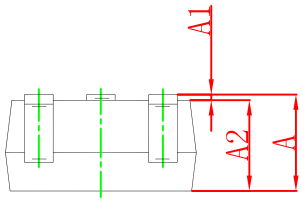
P_C — T_a



SOT-323 Package Outline Dimensions

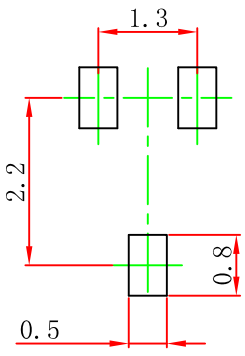






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-323 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.